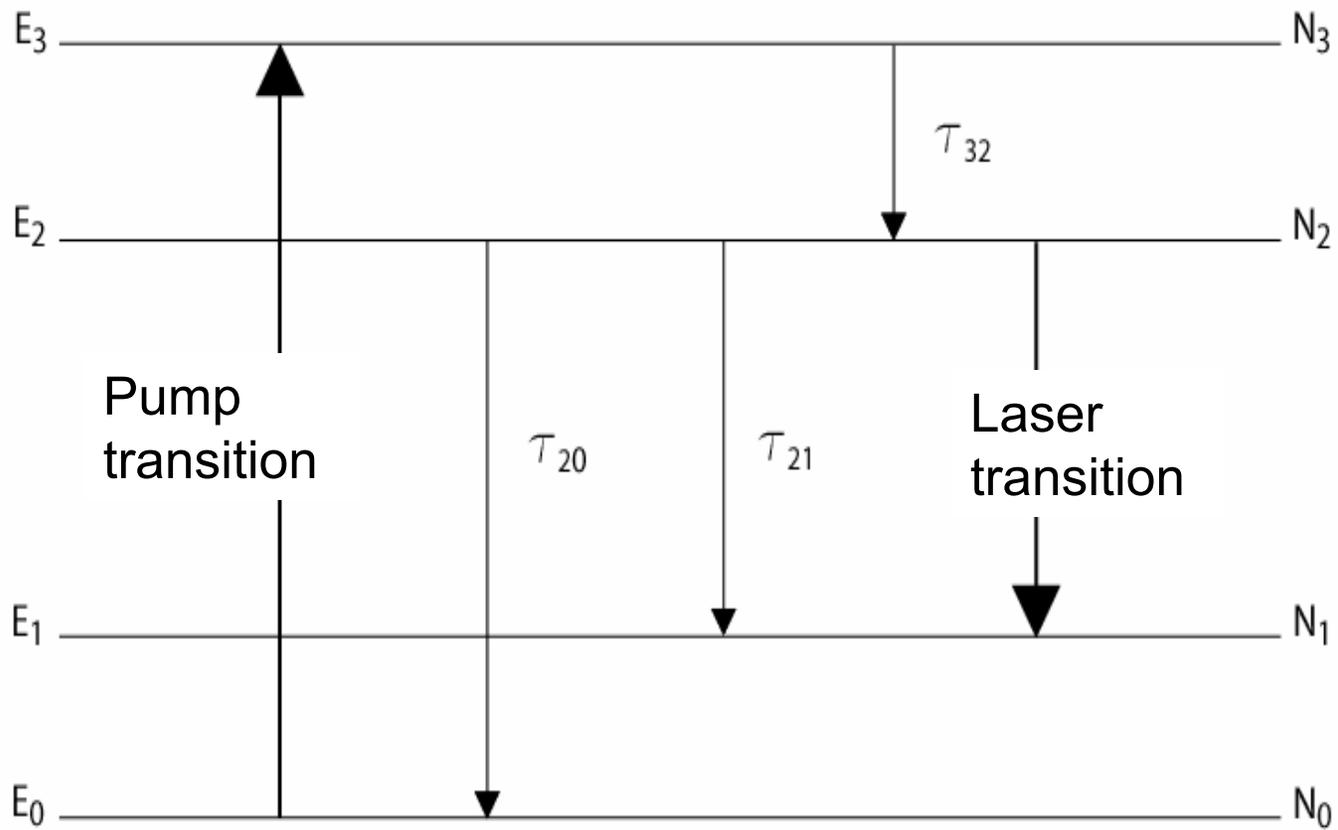


# **Computation of Laser Power Output for CW Operation**

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Energy levels, population numbers, and transitions for a 4-level laser system

## Rate Equations for a 4-Level System

$$\frac{\partial N}{\partial t} = R_p - WN - \frac{N}{\tau}, \quad \frac{dS_L}{dt} = \iiint_a WN dV - \frac{S_L}{\tau_c}$$

$N(x,y,z) = N_2 - N_1$  population inversion density ( $N_1 \sim 0$ )

$R_p$  pump rate

$W(x,y,z)$  transition rate due to stimulated emission

$\tau$  spontaneous fluorescence life time of upper laser level

$S_L$  number of laser photons in the cavity

$\tau_c$  mean life time of laser photons in the cavity

The **pump rate** is given by

$$R_p = \eta_p S_p P_0$$

- $\eta_p$  pump efficiency
- $p_0(x,y,z)$  absorbed pump power density distribution normalized over the crystal volume
- $S_p$  total number of pump photons absorbed in the crystal per unit of time

The **transition rate due to stimulated emission** is given by

$$W = \frac{c\sigma}{n} S_L s_0(x, y, z)$$

$\sigma$       stimulated emission cross section

$n$       refractive index of laser material

$s_0(x,y,z)$       normalized distribution of the laser photons

## Detailed Rate Equations of a 4-Level Systems

$$\frac{\partial N}{\partial t} = R_p - N \frac{c\sigma}{n} S_L s_0(x, y, z) - \frac{N}{\tau}$$

$$\frac{dS}{dt} = S_L \left[ \iiint_a \frac{c\sigma}{n} N s_0(x, y, z) dV - \frac{1}{\tau_c} \right]$$

Condition for equilibrium

$$\partial N / \partial t = dS / dt = 0$$

Using the equilibrium conditions, and carrying through some transformations one is getting a recursion relation for the number of laser photons in the cavity

$$S_L = \tau_c \eta_p S_P \iiint_a \frac{p_0(x, y, z)}{1 + \frac{n}{c\sigma\tau S_L s_0(x, y, z)}} dV$$

This equation can be solved by iterative integration. The integral extends over the volume of the active medium. The iteration converges very fast, as starting condition

$$S_L = \tau_c \eta_p S_P$$

can be used.

The laser power output is obtained by computing the number of photons passing the output coupler per time unit. This delivers for the power output the relation

$$P_{out} = h \nu_L S_L \frac{c(-\ln(R_{out}))}{2\tilde{L}}$$

$R_{out}$  reflectivity of output mirror

$c$  vacuum speed of light

$\nu_L$  frequency of laser light

$h$  Planck's constant

$\tilde{L} = L_r + (n - 1)L_a$  optical path length

To compute  $\tau_c$  we divide the time  $t$  for one round-trip

$$t = \frac{2\tilde{L}}{c}$$

by the total loss  $T_T$  during one round-trip

$$T_T = L_{roundtrip} - \ln(R_{out})$$

Here  $L_{roundtrip}$  represents all losses during one roundtrip additional to the loss at the output coupler. Using the above expression one obtains

$$\tau_c = \frac{2\tilde{L}}{c(L_{roundtrip} - \ln(R_{out}))}$$

Using the above relations one obtains for the laser power output the recursion relation

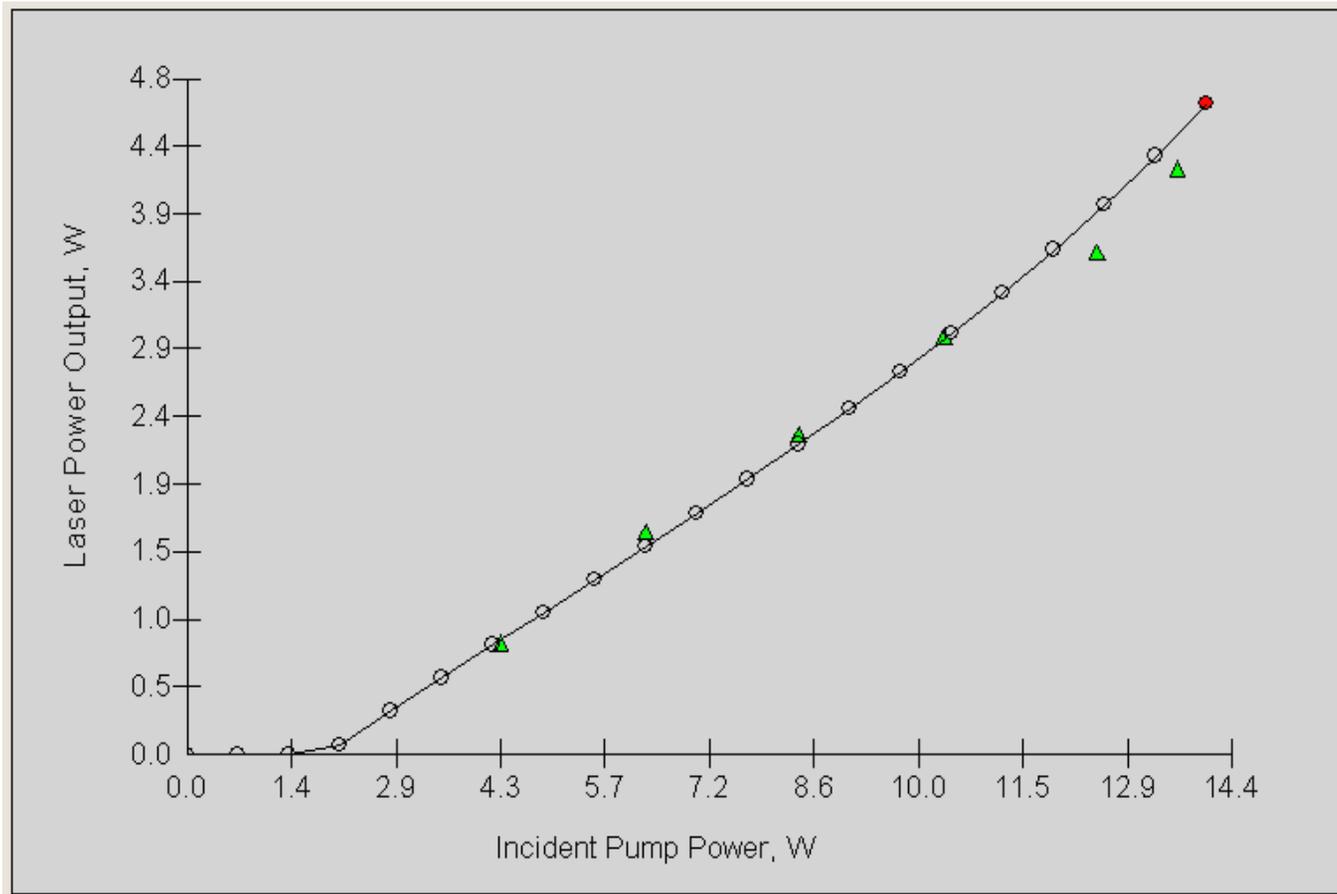
$$P_{out} = \eta_p P_P \frac{h \nu_L}{h \nu_P} \frac{-\ln(R_{out})}{T_T} \iiint_a \frac{p_0}{1 + \frac{n h \nu_L c T_M}{2 P_{out} \tilde{L} s_0 c \sigma \tau}} dV$$

Here

$$P_P = h \nu_P S_P$$

is the totally absorbed pump power per time unit,  
 $\nu_P$  is the frequency of the pump light

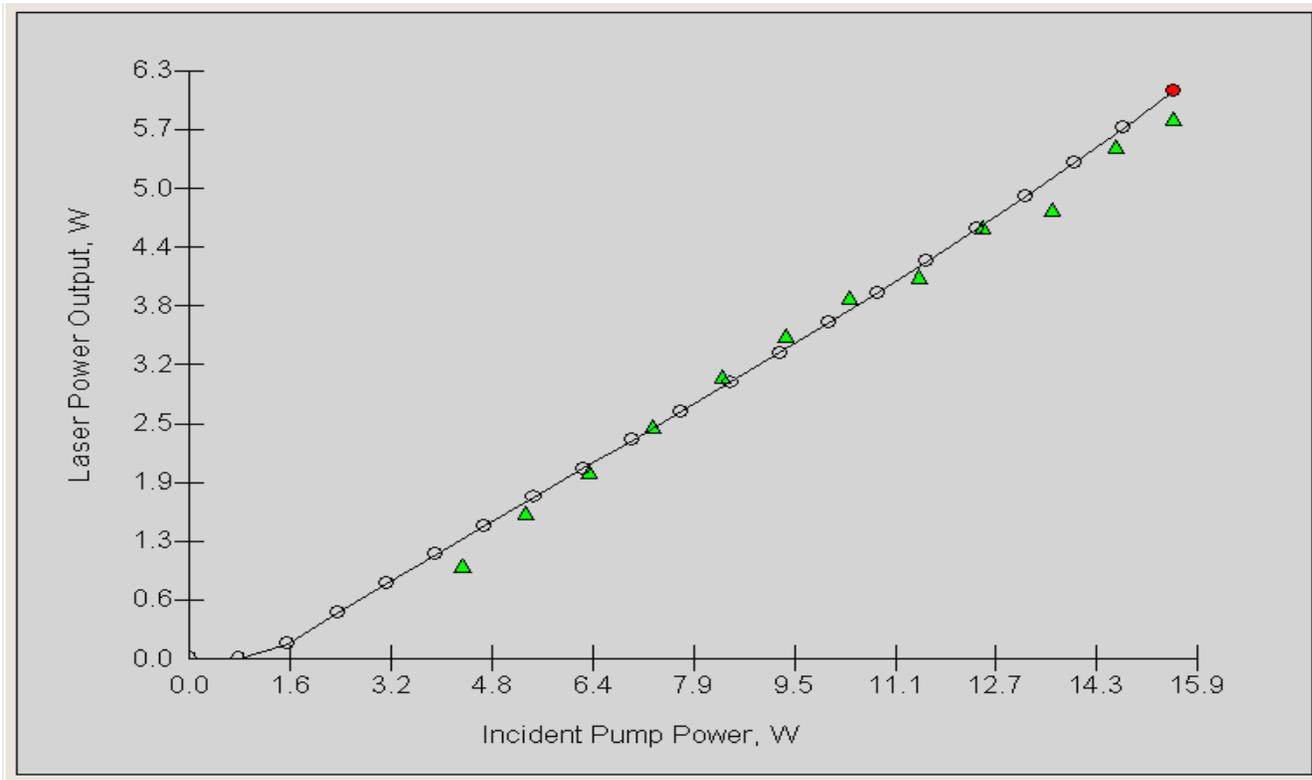
The next viewgraphs are showing results of comparison between experimental measurements and simulation for Nd:YAG and Nd:YVO4. The agreement between the results turned out to be very good.



Power output vs. pump power for 1.1 at.% Nd:YAG

▲ Measurement

o—o Computation

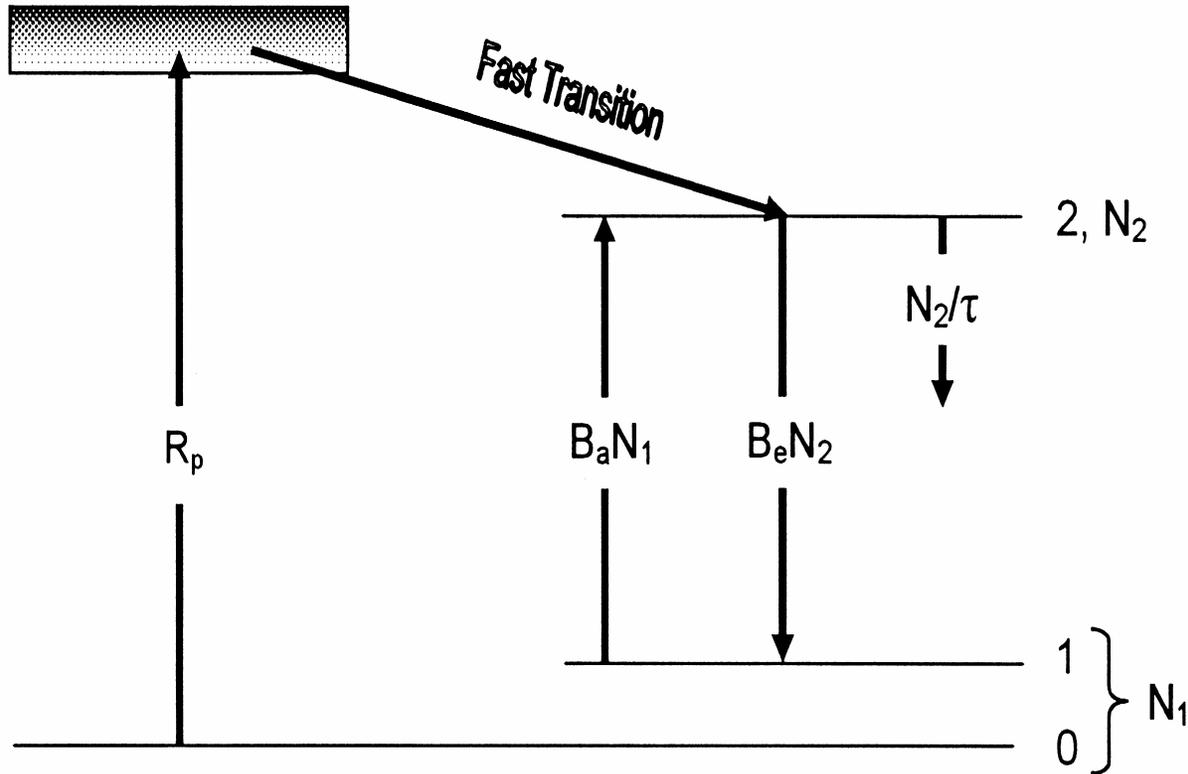


Power output vs. pump power for 0.27 at.% Nd:YVO<sub>4</sub>

▲ Measurement

o—o Computation

In similar way the laser power output for a quasi-3-level laser system can be computed



Energy levels, population numbers, and transitions for a quasi-3-level laser system

## Rate Equations for a Quasi-3-Level System

$$N_t = N_1 + N_2$$

$$\frac{\partial N_2}{\partial t} = R_p - B_e N_2 + B_a N_1 - \frac{N_2}{\tau}$$

$$\frac{\partial S_L}{\partial t} = \iiint_a (B_e N_2 - B_a N_1) dV - \frac{S_L}{\tau_C}$$

$N_t$  doping density per unit volume

$B_e$  transition rate for stimulated emission

$$B_e = \frac{c\sigma_e}{n} S_L s_0(x, y, z)$$

$B_a$  transition rate for reabsorption

$$B_a = \frac{c\sigma_a}{n} S_L s_0(x, y, z)$$

$\sigma_e(T(x,y,z))$  effective cross section of stimulated emission

$\sigma_a$  effective cross section of reabsorption

$c$  the vacuum speed of light

To solve the rate equation again equilibrium conditions are used

$$\partial N / \partial t = dS / dt = 0$$

After some transformations this recursion relation is obtained

$$P_{out} = \frac{hcT_M}{\lambda_L T_T} \iiint_a \frac{q_\sigma \eta_p \lambda_p P_p p_0 / (hc) - (q_\sigma - 1) N_t / \tau}{q_\sigma + \frac{hc T_M}{P_{out} (s_{GR} + s_{GL}) \sigma \tau \lambda_L}} dV$$

This recursion relation differs from the relation for 4-level-systems only due to the term

$$q_\sigma = 1 + \frac{\sigma_a}{\sigma_e}$$

$$\sigma_a \rightarrow 0 \quad \Rightarrow \quad q_\sigma \rightarrow 1$$

For  $q_\sigma = 1$  the above relation goes over into the relation for 4-level systems

The parameter  $q_\sigma$  depends on temperature distribution due to temperature dependence of the cross section  $\sigma_e$  of stimulated emission.  $\sigma_e$  can be computed by the use of the method of reciprocity. As shown in the paper of Laura L. DeLoach et al. , IEEE J. of Q. El. **29**, 1179 (1993) the following relation can be deduced

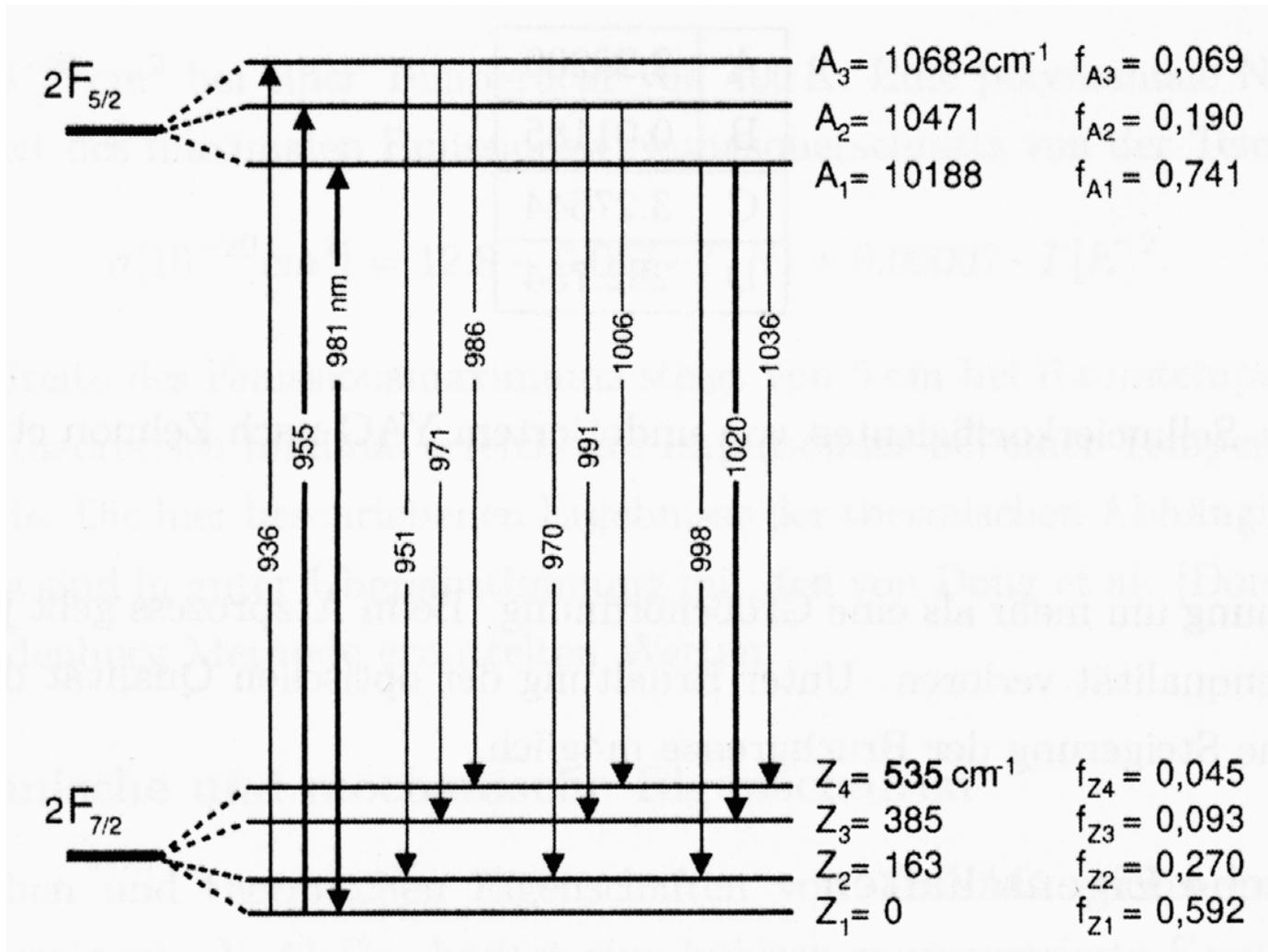
$$\sigma_e = \sigma_a \frac{Z_l(T(x, y, z))}{Z_u(T(x, y, z))} \exp\left(\frac{E_{zL} - h\nu}{kT(x, y, z)}\right)$$

$Z_u$  and  $Z_l$  are the partition functions of the upper and lower crystal field states

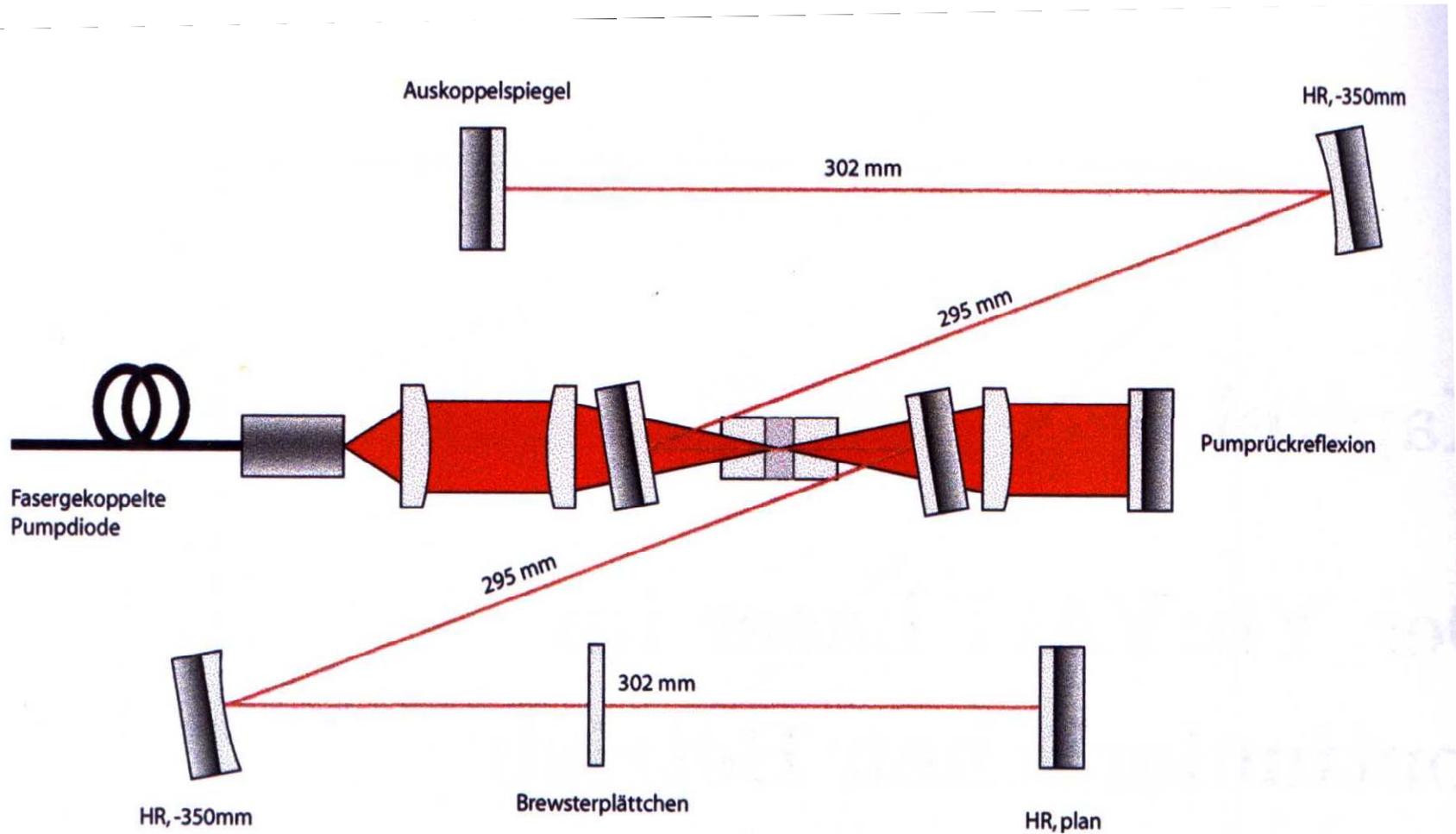
$E_{zL}$  is the energy separation between lowest components of the upper and the lower crystal field states.

$k$  is Boltzmann's constant

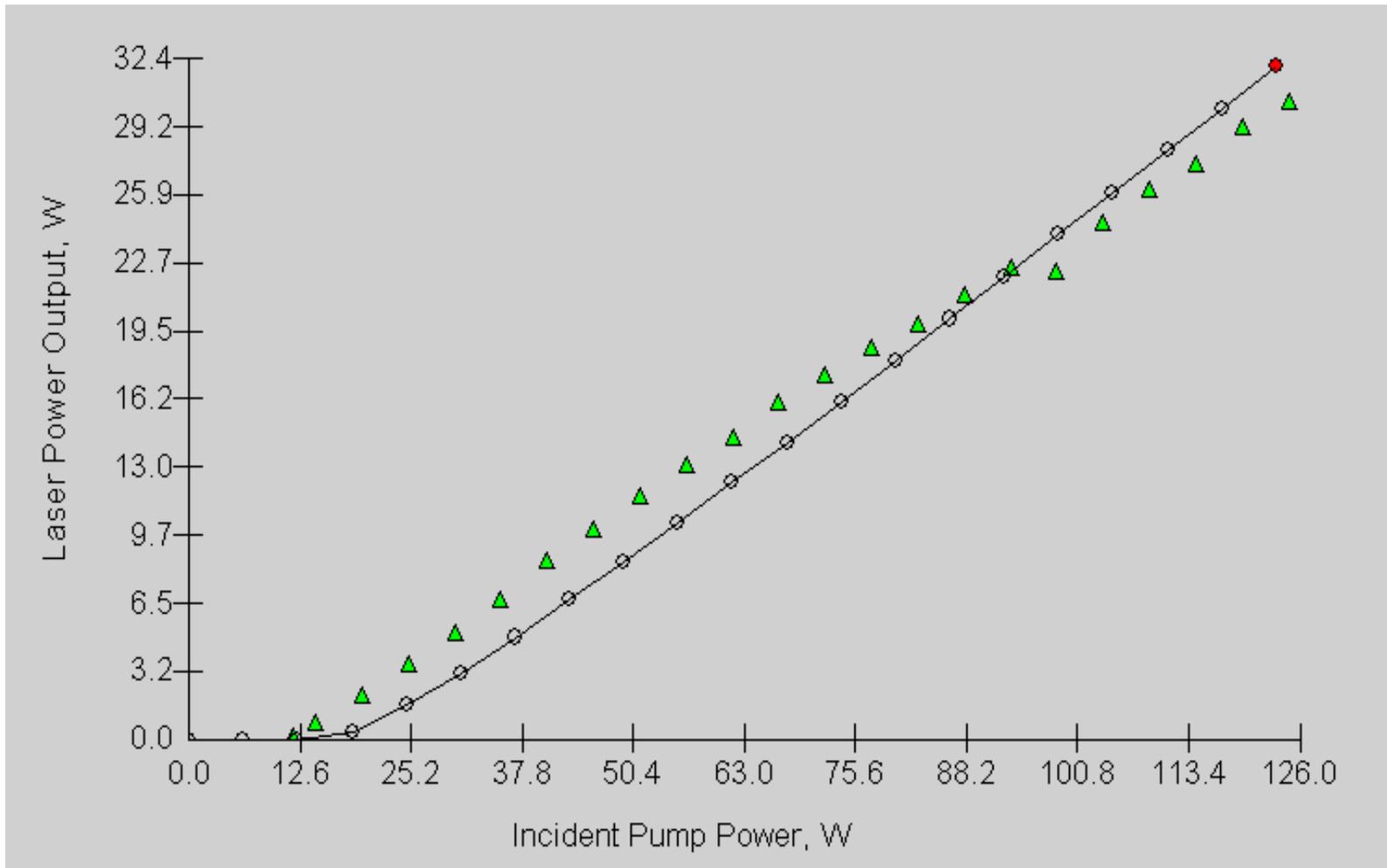
$T(x,y,z)$  [K] is the temperature distribution in the crystal as obtained from FEA.



Energy levels and transitions for the Quasi-3-Level-Material Yb:YAG



Yb:YAG cw-Laser, Laser Group Univ. Kaiserslautern



## Output vs. Input Power for a 5 at. % Yb:YAG Laser

▲ Measurements: Laser Group, Univ. Kaiserslautern

○—○ Computation Using Temperature Dep. Stim. Em. Cross Section